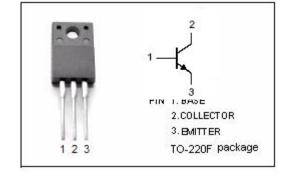




# **isc Silicon NPN Power Transistor**

#### **DESCRIPTION**

- · Low Collector Saturation Voltage-
- : V<sub>CE(sat)</sub>= 1.0 (Max)@ I<sub>C</sub>= 2.5A
- · High Power Dissipation-
- : P<sub>C</sub>= 25W@ T<sub>C</sub>= 25℃
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

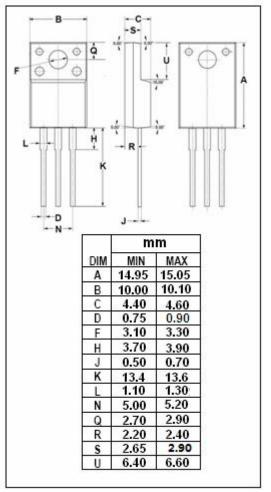


### **APPLICATIONS**

Designed for power amplifier applications

## ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25℃)

SYMBOL	PARAMETER	VALUE	UNIT	
V <sub>CBO</sub>	Collector-Base Voltage	60	V	
V <sub>CEO</sub>	Collector-Emitter Voltage	60		
V <sub>EBO</sub>	Emitter-Base Voltage 7		V	
Ic	Collector Current-Continuous	4	А	
lв	Base Current-Continuous	1	А	
P <sub>C</sub>	Collector Power Dissipation @ T <sub>a</sub> =25℃	2	2 W 25	
	Collector Power Dissipation @ T <sub>C</sub> =25℃	25		
Тл	Junction Temperature	150	$^{\circ}$ C	
T <sub>stg</sub>	Storage Temperature Range	-55~150	$^{\circ}$	





## isc Silicon NPN Power Transistor

2SD2531

### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA ; I <sub>B</sub> = 0	60			V
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 2.5A; I <sub>B</sub> = 0.25A			1.0	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 0.5A ; V <sub>CE</sub> = 5V			1.0	V
Ісво	Collector Cutoff Current	V <sub>CB</sub> = 60V ; I <sub>E</sub> = 0			100	μА
I <sub>EBO</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 7V ; I <sub>C</sub> = 0			100	μА
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 0.5A; V <sub>CE</sub> = 5V	100		320	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 3A ; V <sub>CE</sub> = 5V	20			
f⊤	Current-Gain—Bandwidth Product	I <sub>C</sub> = 0.5A ; V <sub>CE</sub> = 5V		3		MHz
Сов	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f <sub>test</sub> = 1.0MHz		35		pF

### **Notice:**

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications.

ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.